

ANTREX Electronics

Electronic Components Sourcing Information

Product Reference Information

Part Number: NB3V1102CDTR2G
Manufacturer: onsemi
Package: 8-TSSOP (0.173", 4.40mm Width)
Availability: Please confirm with sales

Product Page:

<https://antrexco.com/product/details/onsemi/nb3v1102cdtr2g.html>

Request a Quote:

[Submit RFQ for this part](#)



Scan for product page

Contact Information

Email: info@antrexco.com

WhatsApp: +86-186-8066-5326

Website: <https://antrexco.com>

Quality & Trust

New & Original Components

Supplier verification and packaging condition review

CoC / RoHS / REACH documents available on request

Secure sourcing support for OEM / EMS projects

Note:

This PDF includes an ANTREX product reference cover page.

The original manufacturer datasheet follows from the next page.

3.3 V / 2.5 V / 1.8 V LVCMOS Low Skew Fanout Buffer Family

NB3V110xC Series

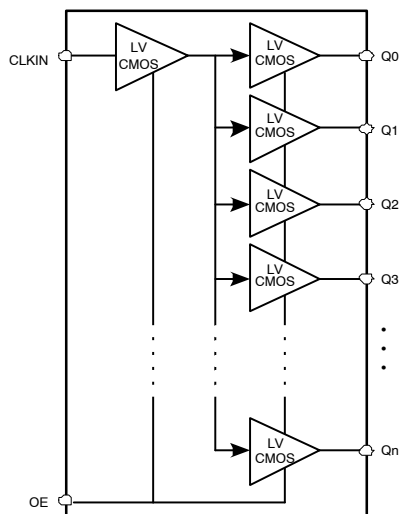
Description

The NB3V110xC are a modular, high-performance, low-skew, general purpose LVCMOS clock buffer family. The family of devices is designed with a modular approach. Four different fan-out variations, 1:2, 1:3, 1:4, 1:6 and 1:8, are available. All of the devices are pin compatible to each other for easy handling. All family members share the same high performing characteristics like low additive jitter, low skew, and wide operating temperature range. The NB3V110xC supports an asynchronous output enable control (OE) which switches the outputs into a low state when OE is low. The NB3V110xC devices operate in a 3.3 V, 2.5 V and 1.8 V environment and are characterized for operation from -40°C to 105°C .

Features

- Operating Temperature Range: -40°C to 105°C
- High-Performance 1:2, 1:3, 1:4, 1:6, 1:8 LVCMOS Clock Buffer
- Available in 8-, 14-, 16-Pin TSSOP and WDFN8 Packages
- Very Low Output-to-Output Skew < 50 ps
- Very Low Additive Jitter < 200 fs
- Supply Voltage: 3.3 V, 2.5 V or 1.8 V
- $f_{\text{max}} = 250 \text{ MHz}$ for 3.3 V; $f_{\text{max}} = 180 \text{ MHz}$ for 2.5 V;
 $f_{\text{max}} = 133 \text{ MHz}$ for 1.8 V
- These Devices are Pb-Free and are RoHS Compliant

BLOCK DIAGRAM



TSSOP-8
DT SUFFIX
CASE 948S



TSSOP-14
DT SUFFIX
CASE 948G

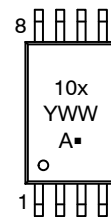


TSSOP-16
DT SUFFIX
CASE 948F

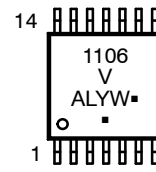


WDFN8, 2x2
MT SUFFIX
CASE 511AT

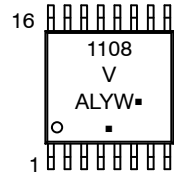
MARKING DIAGRAMS



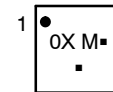
TSSOP-8



TSSOP-14



TSSOP-16



WDFN8

A = Assembly Location
M = Date Code
L = Wafer Lot
Y = Year
W, WW = Work Week
■ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering, marking and shipping information on page 9 of this data sheet.

NB3V110xC Series

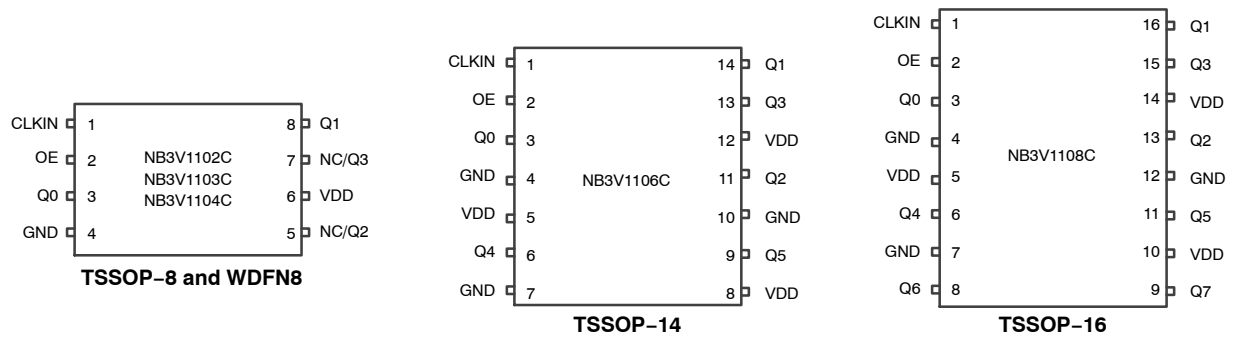


Figure 1. Pin Configuration

Table 1. PIN DESCRIPTION

	LVC MOS Clock Input	LVC MOS Clock Output Enable	LVC MOS Clock Output	Device Supply Voltage	Device Ground
Devices	CLKIN	OE	Q0, Q1, ... Q7	V _{DD}	GND
NB3V1102C	1	2	3, 8	6	4
NB3V1103C	1	2	3, 8, 5	6	4
NB3V1104C	1	2	3, 8, 5, 7	6	4
NB3V1106C	1	2	3, 14, 11, 13, 6, 9	5, 8, 12	4, 7, 10
NB3V1108C	1	2	3, 16, 13, 15, 6, 11, 8, 9	5, 10, 14	4, 7, 12

NOTE: Pins not mentioned in the table are NC.

Table 2. OUTPUT LOGIC TABLE

INPUTS		OUTPUTS
CLKIN	OE	Q _n
X	L	L
L	H	L
H	H	H

Table 3. ATTRIBUTES

Characteristic	Value	Unit
ESD Protection	Human Body Model (HBM) per ANSI/ESDA/JEDEC JS-001-2014 Charged Device Model (CDM) per ANSI/ESDA/JEDEC JS-002-2014	5000 1500 V V
Moisture Sensitivity, Indefinite Time Out of Dry Pack (Note 1)	Level 1	–
Meets or exceeds JEDEC Spec JESD78D (LU) IC Latchup Test		

1. JEDEC standard multilayer board – 2S2P (2 signal, 2 power) with a large copper heat spreader (20 mm², 2 oz.)

NB3V110xC Series

Table 4. ABSOLUTE MAXIMUM RATINGS (Note 2)
Over operating free-air temperature range (unless otherwise noted)

Symbol	Condition		Value	Unit
V_{DD}	Supply Voltage Range		−0.5 to 4.6	V
V_{IN}	Input Voltage Range (Note 3)		−0.5 to $V_{DD} + 0.5$	V
V_O	Output Voltage Range (Note 3)		−0.5 to $V_{DD} + 0.5$	V
I_{IN}	Input Current		±20	mA
I_O	Continuous Output Current		±50	mA
θ_{JA}	Thermal Resistance (Junction-to-Ambient)	TSSOP-8	151.2*	°C/W
		TSSOP-14	104*	
		TSSOP-16	32*	
			110**	
		WDFN8	190**	
θ_{JC}	Thermal Resistance (Junction-to-Case top)	TSSOP-8	35	°C/W
		TSSOP-14	8.6	
		TSSOP-16	10	
		WDFN8	10	
T_J	Maximum Junction Temperature		125	°C
T_{STG}	Storage Temperature Range		−65 to 150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

2. JEDEC standard multilayer board – 2S2P (2 signal, 2 power) with a large copper heat spreader (20 mm², 2 oz.)

3. For additional information, see Application Note AND8003/D.

*JEDEC51.7 four layer PCB with 100 sqmm, 2 oz with two 80x80x1oz ground planes.

**JEDEC51.3 two layer PCB with 100 sqmm, 2 oz.



NB3V110xC Series

Table 5. RECOMMENDED OPERATING CONDITIONS

Over operating free-air temperature range (unless otherwise noted)

Symbol	Condition	Min	Typ	Max	Unit
V_{DD}	Supply voltage range	3.3 V supply	3.0	3.3	3.6
		2.5 V supply	2.3	2.5	2.7
		1.8 V supply	1.71	1.8	1.89
V_{IL}	Low-level input voltage	$V_{DD} = 3.0 \text{ V to } 3.6 \text{ V}$			$V_{DD}/2 - 600$
		$V_{DD} = 2.3 \text{ V to } 2.7 \text{ V}$			$V_{DD}/2 - 400$
		$V_{DD} = 1.71 \text{ V to } 1.89 \text{ V}$			$0.3 \times V_{DD}$
V_{IH}	High-level input voltage	$V_{DD} = 3.0 \text{ V to } 3.6 \text{ V}$	$V_{DD}/2 + 600$		
		$V_{DD} = 2.3 \text{ V to } 2.7 \text{ V}$	$V_{DD}/2 + 400$		
		$V_{DD} = 1.71 \text{ V to } 1.89 \text{ V}$	$0.7 \times V_{DD}$		
V_{th}	Input threshold voltage	$V_{DD} = 2.3 \text{ V to } 3.6 \text{ V}$	$V_{DD}/2$		V
		$V_{DD} = 1.71 \text{ V to } 1.89 \text{ V}$	$V_{DD}/2$		V
t_r / t_f	Input slew rate (Note 4)		1		4
t_w	Minimum pulse width at CLKIN	$V_{DD} = 3.0 \text{ V to } 3.6 \text{ V}$	1.8		
		$V_{DD} = 2.3 \text{ V to } 2.7 \text{ V}$	2.75		
		$V_{DD} = 1.71 \text{ V to } 1.89 \text{ V}$	3.75		
fCLK	LVCMOS clock Input Frequency	$V_{DD} = 3.0 \text{ V to } 3.6 \text{ V}$	DC		250
		$V_{DD} = 2.3 \text{ V to } 2.7 \text{ V}$	DC		180
		$V_{DD} = 1.71 \text{ V to } 1.89 \text{ V}$	DC		133
T_A	Operating free-air temperature	-40		105	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

4. Guaranteed by Design.



NB3V110xC Series

Table 6. DEVICE CHARACTERISTICS Over recommended operating free-air temperature range (unless otherwise noted) (Note 5)

Symbol	Parameter	Condition	Min	Typ	Max	Unit
OVERALL PARAMETERS FOR ALL VERSIONS						
I _{DD}	Static device current	OE = V _{DD} ; CLKIN = 0 V or V _{DD} ; I _O = 0 mA; V _{DD} = 3.6 V			0.2	mA
		OE = V _{DD} ; CLKIN = 0 V or V _{DD} ; I _O = 0 mA; V _{DD} = 2.7 V			0.2	
		OE = V _{DD} ; CLKIN = 0 V or V _{DD} ; I _O = 0 mA; V _{DD} = 1.89 V			0.2	
I _{PD}	Power down current	OE = 0 V; CLKIN = 0 V or V _{DD} ; I _O = 0 mA; V _{DD} = 3.6 V, 2.7 V or 1.89 V (For 1102C, 1103C, 1104C)			60	μA
		OE = 0 V; CLKIN = 0 V or V _{DD} ; I _O = 0 mA; V _{DD} = 3.6 V, 2.7 V or 1.89 V (For 1106C, 1108C)			75	
C _{PD}	Power dissipation capacitance per output (Note 6)	V _{DD} = 3.3 V; f = 10 MHz		9		pF
		V _{DD} = 2.5 V; f = 10 MHz		9		
		V _{DD} = 1.8 V; f = 10 MHz		9		
I _I	Input leakage current at OE	V _I = 0 V or V _{DD} , V _{DD} = 3.6 V or 2.7 V			± 8	μA
	Input leakage current at CLKIN				± 8	
	Input leakage current at OE, CLKIN	V _I = 0 V or V _{DD} , V _{DD} = 1.89 V			± 8	
R _{OUT}	Output impedance	V _{DD} = 3.3 V		40		Ω
		V _{DD} = 2.5 V		45		
		V _{DD} = 1.8 V		60		
f _{OUT}	Output frequency	V _{DD} = 3.0 V to 3.6 V	DC		250	MHz
		V _{DD} = 2.3 V to 2.7 V	DC		180	
		V _{DD} = 1.71 V to 1.89 V	DC		133	

OUTPUT PARAMETERS FOR V_{DD} = 3.3 V ± 0.3 V

V _{OH}	High-level output voltage	V _{DD} = 3 V, I _{OH} = -0.1 mA	2.9			V
		V _{DD} = 3 V, I _{OH} = -8 mA	2.5			
		V _{DD} = 3 V, I _{OH} = -12 mA	2.2			
V _{OL}	Low-level output voltage	V _{DD} = 3 V, I _{OL} = 0.1 mA			0.1	V
		V _{DD} = 3 V, I _{OL} = 8 mA			0.5	
		V _{DD} = 3 V, I _{OL} = 12 mA			0.8	
t _{PLH} , t _{PHL}	Propagation delay (Note 7)	CLKIN to Qn	0.8		2.0	ns
t _{sk(o)}	Output skew (Note 7)	Equal load of each output 85°C			50	ps
		Equal load of each output 105°C			60	
t _r /t _f	Rise and fall time	20%–80% (V _{OH} - V _{OL})	0.12		0.8	ns
t _{DIS}	Output disable time (Note 7)	OE to Qn			6	ns
t _{EN}	Output enable time (Note 7)	OE to Qn			6	ns
t _{sk(p)}	Pulse skew; t _{PLH} (Qn) - t _{PHL} (Qn) (Note 8)	To be measured with input duty cycle of 50%			180	ps
t _{sk(pp)}	Part-to-part skew	Under equal operating conditions for two parts			0.5	ns
T _{jitt(φ)}	Additive jitter rms	12 kHz...20 MHz f _{OUT} = 100 MHz			100	fs
		12 kHz...20 MHz f _{OUT} = 156.25 MHz				

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

5. All typical values are at respective nominal V_{DD}. For switching characteristics, outputs are terminated to 50 Ω to V_{DD}/2 (see Figure 2).

6. This is the formula for the power dissipation calculation.

$$P_{tot} = P_{stat} + P_{dyn} + P_{Cload} [W] \quad P_{stat} = V_{DD} \times I_{DD} [W]$$

$$P_{dyn} = C_{PD} \times V_{DD}^2 \times f \times n [W]$$

$$P_{Cload} = C_{load} \times V_{DD}^2 \times f \times n [W]$$

n = Number of switching output pins

7. With rail to rail input clock.

8. t_{sk(p)} depends on output rise- and fall-time (t_r/t_f). The output duty-cycle can be calculated: odc = (t_{w(OUT)} ± t_{sk(p)})/t_{period}; t_{w(OUT)} is pulse-width of ideal output waveform and t_{period} is 1/f_{OUT}.



NB3V110xC Series

Table 7. DEVICE CHARACTERISTICS (continued)

Over recommended operating free-air temperature range (unless otherwise noted) (Note 5)

Symbol	Parameter	Condition	Min	Typ	Max	Unit
OUTPUT PARAMETERS FOR $V_{DD} = 2.5 \text{ V} \pm 0.2 \text{ V}$						
V_{OH}	High-level output voltage	$V_{DD} = 2.3 \text{ V}, I_{OH} = -0.1 \text{ mA}$	2.2			V
		$V_{DD} = 2.3 \text{ V}, I_{OH} = -8 \text{ mA}$	1.7			
V_{OL}	Low-level output voltage	$V_{DD} = 2.3 \text{ V}, I_{OL} = 0.1 \text{ mA}$			0.1	V
		$V_{DD} = 2.3 \text{ V}, I_{OL} = 8 \text{ mA}$			0.5	
t_{PLH}, t_{PHL}	Propagation delay (Note 10)	CLKIN to Qn		1.8		ns
$t_{sk(o)}$	Output skew (Note 10)	Equal load of each output 85°C			50	ps
		Equal load of each output 105°C			60	
t_r/t_f	Rise and fall time	20%–80% ($V_{OH} - V_{OL}$)	0.12		1.2	ns
t_{DIS}	Output disable time (Note 10)	OE to Qn			10	ns
t_{EN}	Output enable time (Note 10)	OE to Qn			10	ns
$t_{sk(p)}$	Pulse skew ; $t_{PLH(Qn)} - t_{PHL(Qn)}$ (Note 9)	To be measured with input duty cycle of 50%			220	ps
$t_{sk(pp)}$	Part-to-part skew	Under equal operating conditions for two parts			1.2	ns
$t_{jit(\phi)}$	Additive jitter rms	12 kHz...20 MHz $f_{OUT} = 100 \text{ MHz}$			150	fs
		12 kHz...20 MHz $f_{OUT} = 156.25 \text{ MHz}$			100	

OUTPUT PARAMETERS FOR $V_{DD} = 1.8 \text{ V} \pm 5\%$

V_{OH}	High-level output voltage	$V_{DD} = 1.71 \text{ V}, I_{OH} = -0.1 \text{ mA}$	1.6			V
		$V_{DD} = 1.71 \text{ V}, I_{OH} = -4 \text{ mA}$	$0.75 \times V_{DD}$			
V_{OL}	Low-level output voltage	$V_{DD} = 1.71 \text{ V}, I_{OL} = 0.1 \text{ mA}$			0.1	V
		$V_{DD} = 1.71 \text{ V}, I_{OL} = 4 \text{ mA}$			$0.25 \times V_{DD}$	
t_{PLH}, t_{PHL}	Propagation delay (Note 10)	CLKIN to Qn	1.8		3.5	ns
$t_{sk(o)}$	Output skew (Note 10)	Equal load of each output			75	ps
t_r/t_f	Rise and fall time	20%–80% ($V_{OH} - V_{OL}$)	0.17		1.2	ns
t_{DIS}	Output disable time (Note 10)	OE to Qn			10	ns
t_{EN}	Output enable time (Note 10)	OE to Qn			10	ns
$t_{sk(p)}$	Pulse skew ; $t_{PLH(Qn)} - t_{PHL(Qn)}$ (Note 9)	To be measured with input duty cycle of 50%			450	ps
$t_{sk(pp)}$	Part-to-part skew	Under equal operating conditions for two parts			1.2	ns
$t_{jit(\phi)}$	Additive jitter rms	12 kHz...20 MHz, $f_{OUT} = 100 \text{ MHz}$			200	fs

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

9. $t_{sk(p)}$ depends on output rise- and fall-time (t_r/t_f). The output duty-cycle can be calculated: $odc = (t_{w(OUT)} \pm t_{sk(p)})/t_{period}$; $t_{w(OUT)}$ is pulse-width of ideal output waveform and t_{period} is $1/f_{OUT}$.

10. With rail to rail input clock.



NB3V110xC Series

PARAMETERS MEASUREMENT INFORMATION

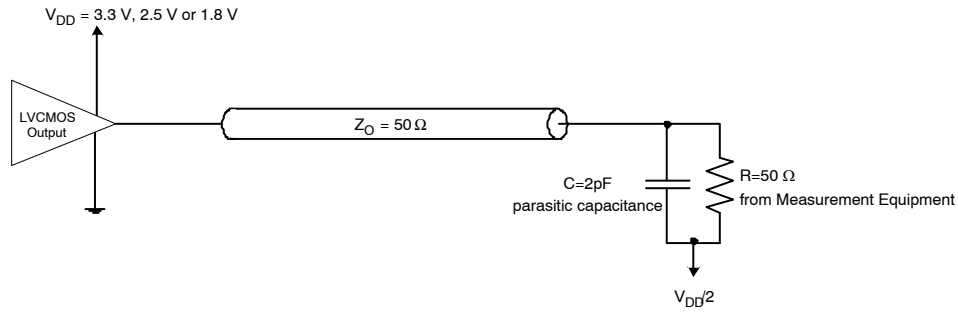


Figure 2. Test Load Circuit

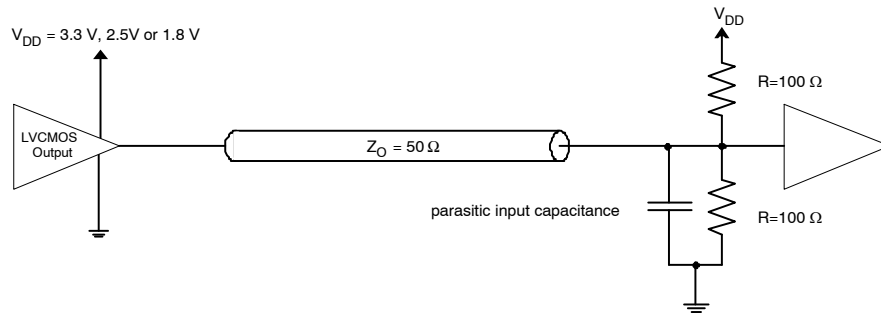


Figure 3. Application Load with $50\ \Omega$ Line Termination

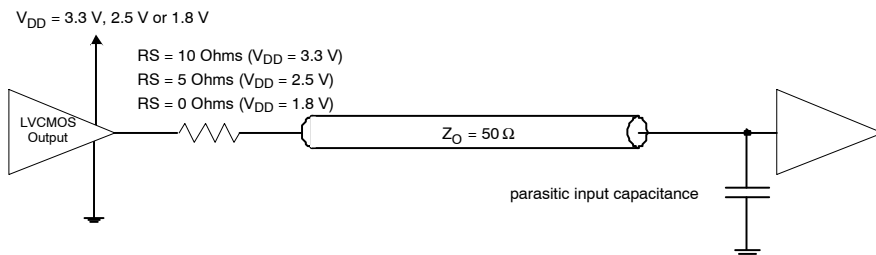


Figure 4. Application Load with Series Line Termination

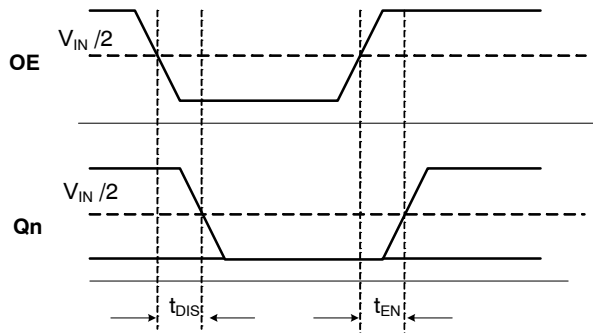


Figure 5. t_{DIS} and t_{EN} for Disable Low

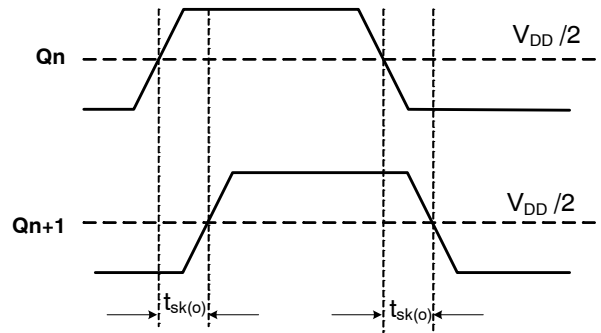


Figure 6. Output Skew $t_{sk(o)}$

NB3V110xC Series

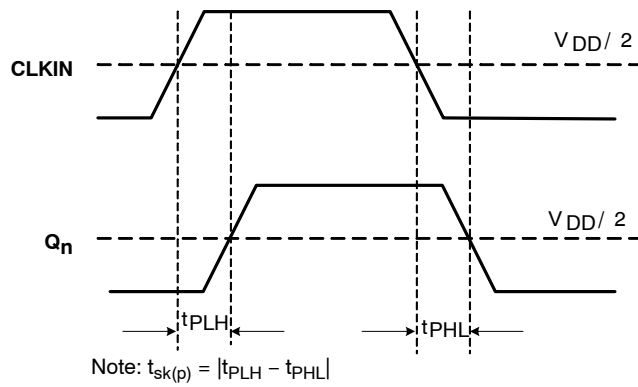


Figure 7. Pulse Skew $t_{sk(p)}$ and Propagation Delay t_{PLH}/t_{PHL}

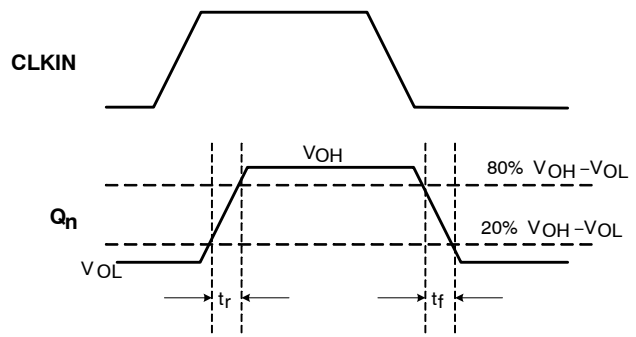


Figure 8. Rise/Fall Times t_r/t_f

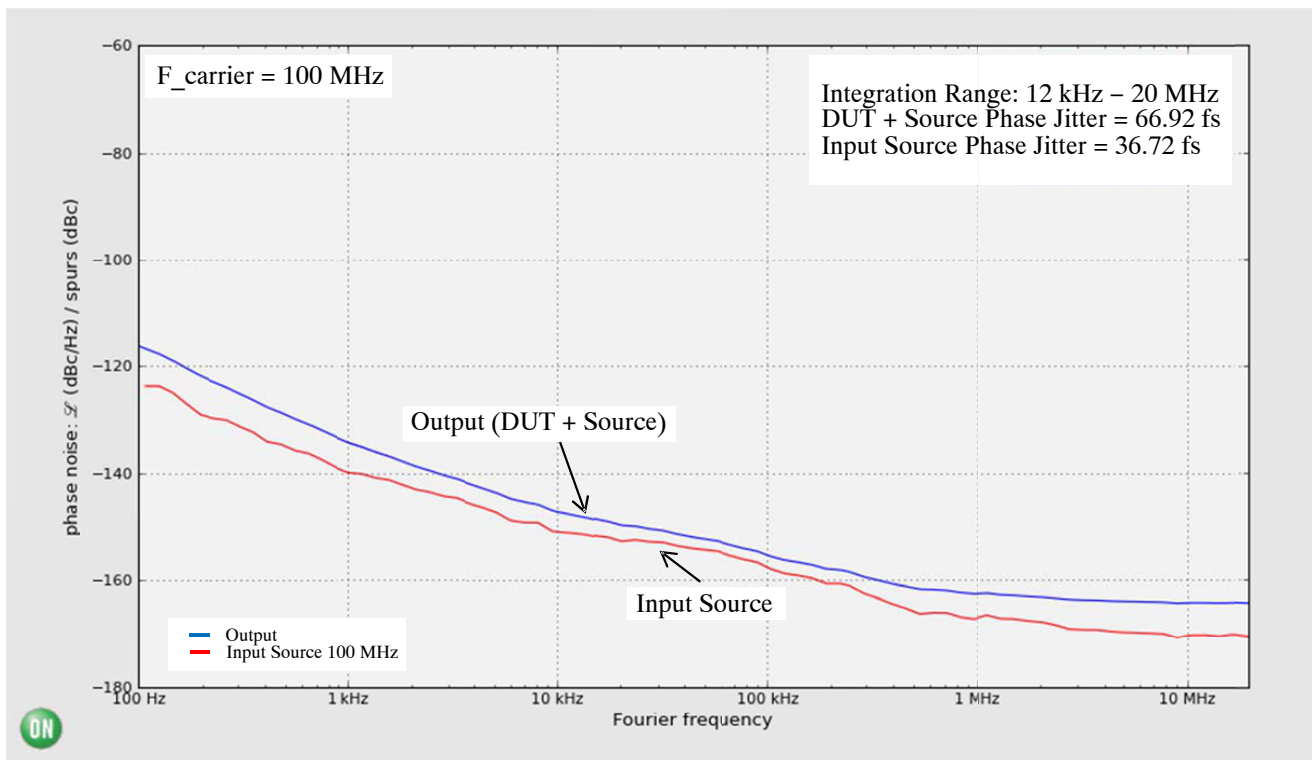


Figure 9. Typical NB3V110xC Phase Noise Plot at $f_{Carrier} = 100$ MHz, $V_{DD} = 3.3$ V, 25°C

The above phase noise data was captured using Agilent E5052A/B. The data displays the input phase noise and output phase noise used to calculate the additive phase jitter at a specified integration range. The additive RMS phase jitter contributed by the device (integrated between 12 kHz and 20 MHz) is 55.94 fs. The additive RMS phase jitter performance of the fan out buffer is highly dependent on the phase noise of the input source.

To obtain the most precise additive phase noise measurement, it is vital that the source phase noise be notably lower than that of the DUT. If the phase noise of the source is greater than the noise floor of the device under test, the source noise will dominate the additive phase jitter calculation and lead to an incorrect negative result for the additive phase noise within the integration range. The Figure above is a good example of the NB3V110xC source generator phase noise having a significantly lower floor than the DUT and results in an additive phase jitter of 55.94 fs.

$$\text{Additive RMS phase jitter} = \sqrt{\text{RMS phase jitter of output}^2 - \text{RMS phase jitter of input}^2}$$

$$55.94 \text{ fs} = \sqrt{66.92 \text{ fs}^2 - 36.72 \text{ fs}^2}$$

NB3V110xC Series

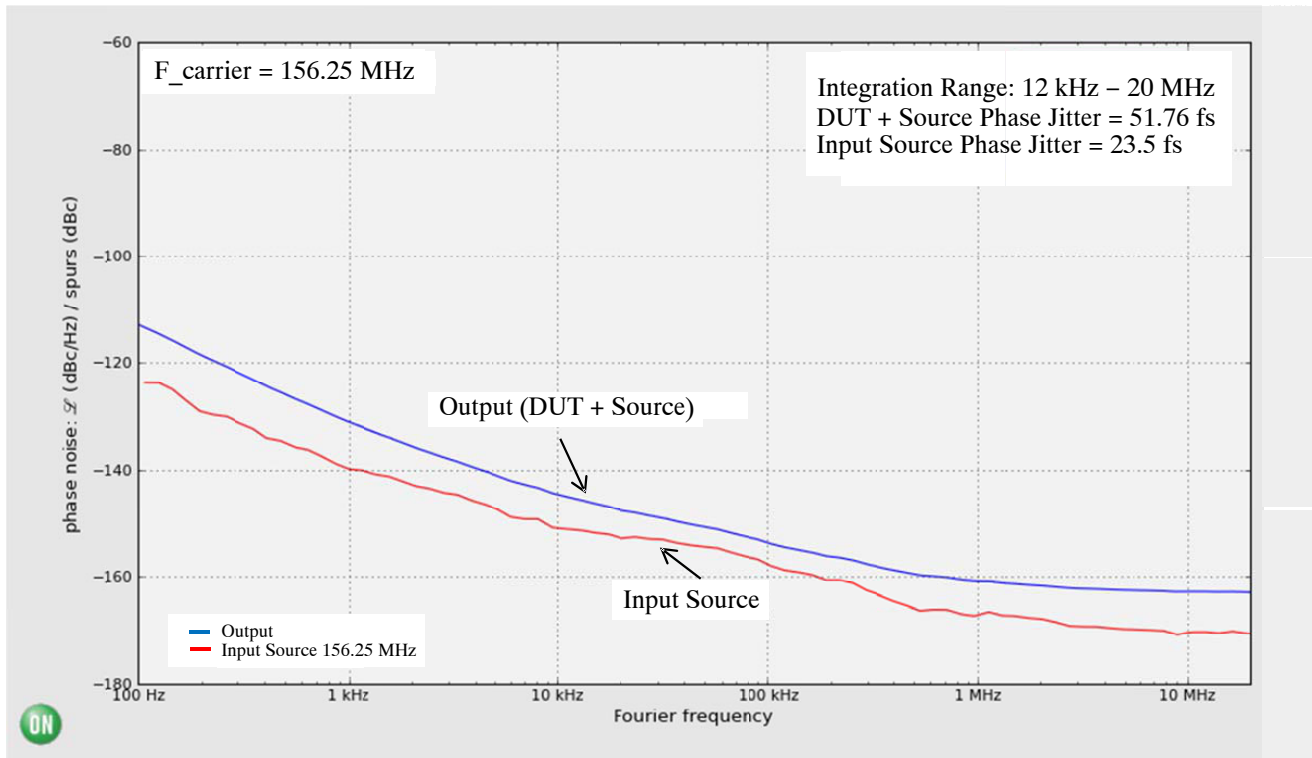


Figure 10. Typical NB3V110xC Phase Noise Plot at $f_{\text{carrier}} = 156.25 \text{ MHz}$, $V_{\text{CC}} = 3.3 \text{ V V}$, 25°C

The additive RMS phase jitter contributed by the device (integrated between 12 kHz and 20 MHz) is 46.11 fs.

$$\begin{aligned} \text{Additive RMS phase jitter} &= \sqrt{\text{RMS phase jitter of output}^2 - \text{RMS phase jitter of input}^2} \\ 46.11 \text{ fs} &= \sqrt{51.76 \text{ fs}^2 - 23.5 \text{ fs}^2} \end{aligned}$$

Figures 9 and 10 were created with measured data from Agilent-E5052A/B Signal Source Analyzer using **onsemi** Phase Noise Explorer web tool. This free application enables an interactive environment for advanced phase

noise and jitter analysis of timing devices and clock tree designs. To see the performance of NB3V110xC beyond conditions outlined in this datasheet, please visit the **onsemi** Green Point Design Tools homepage.

Table 8. ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
NB3V1102CDTR2G	102	TSSOP-8 (Pb-Free)	2500 / Tape & Reel
NB3V1103CDTR2G	103		
NB3V1104CDTR2G	104		
NB3V1102CMTTBG	02	WDFN8 (Pb-Free)	3000 / Tape & Reel
NB3V1104CMTTBG	04		
NB3V1106CDTR2G	1106 V	TSSOP-14 (Pb-Free)	2500 / Tape & Reel
NB3V1108CDTR2G	1108 V	TSSOP-16 (Pb-Free)	2500 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](#).

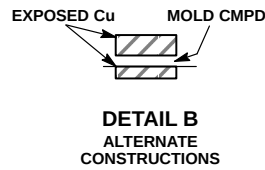
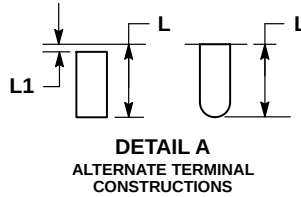
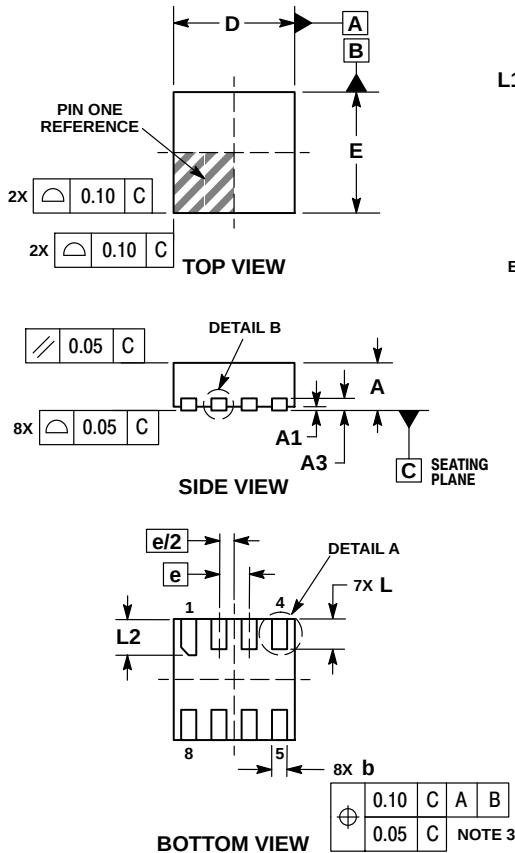
NOTE: Please contact your **onsemi** sales representative for availability of parts in tube.



SCALE 4:1

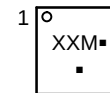
WDFN8 2x2, 0.5P
CASE 511AT
ISSUE O

DATE 26 FEB 2010


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 MM FROM TERMINAL TIP.

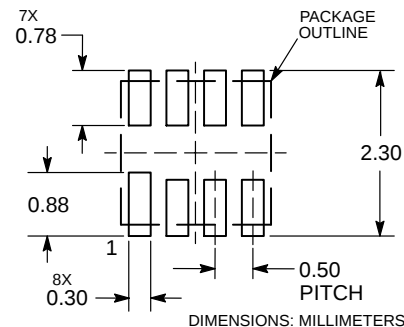
MILLIMETERS		
DIM	MIN	MAX
A	0.70	0.80
A1	0.00	0.05
A3	0.20 REF	
b	0.20	0.30
D	2.00 BSC	
E	2.00 BSC	
e	0.50 BSC	
L	0.40	0.60
L1	---	0.15
L2	0.50	0.70

GENERIC MARKING DIAGRAM*


XX = Specific Device Code
M = Date Code
▪ = Pb-Free Device

(Note: Microdot may be in either location)

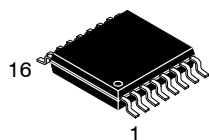
*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present.

RECOMMENDED SOLDERING FOOTPRINT*


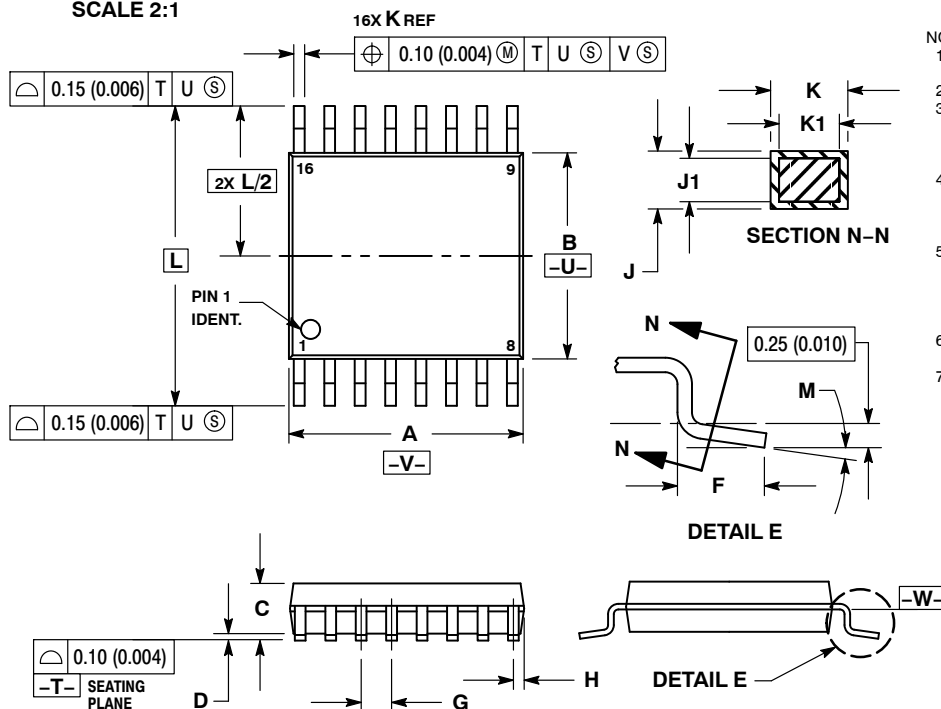
*For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERM/D.

DOCUMENT NUMBER:	98AON48654E	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	WDFN8, 2X2, 0.5 P	PAGE 1 OF 1

onsemi and onsemi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

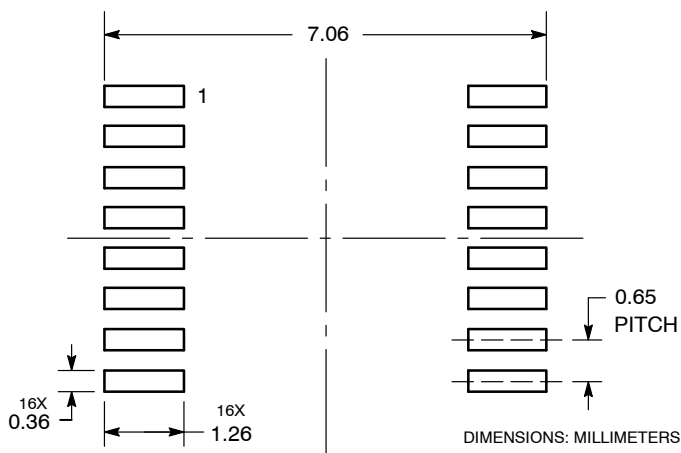

TSSOP-16 WB
CASE 948F
ISSUE B

DATE 19 OCT 2006

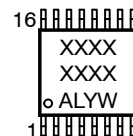

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.90	5.10	0.193	0.200
B	4.30	4.50	0.169	0.177
C	---	1.20	---	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
H	0.18	0.28	0.007	0.011
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0°	8°	0°	8°

**RECOMMENDED
SOLDERING FOOTPRINT***


*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

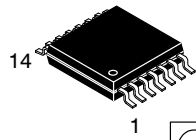
**GENERIC
MARKING DIAGRAM***


XXXX = Specific Device Code
A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week
G or ■ = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

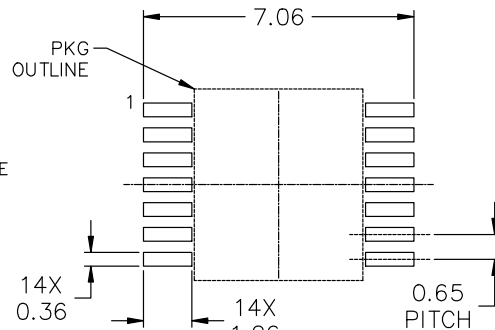
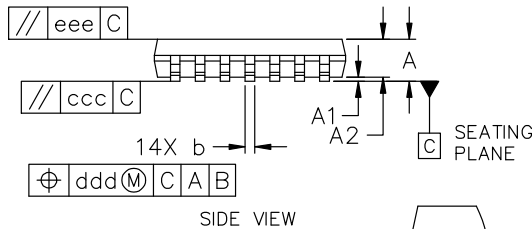
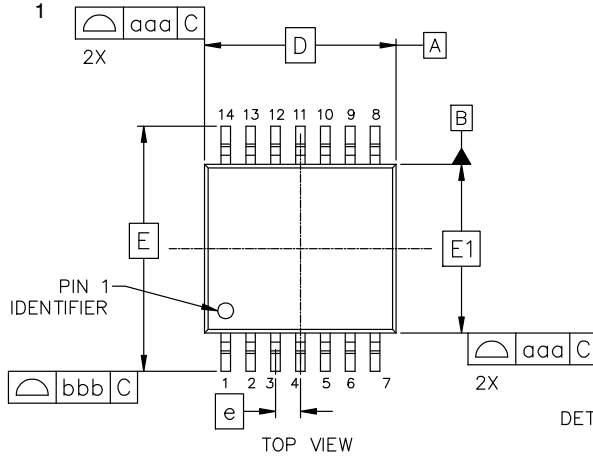
DOCUMENT NUMBER:	98ASH70247A	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	TSSOP-16	PAGE 1 OF 1

onsemi and onsemi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.



TSSOP-14 5.00x4.40x0.95, 0.65P
CASE 948G
ISSUE D

DATE 30 JUN 2026



MILLIMETERS			
DIM	MIN	NOM	MAX
A	---	---	1.20
A1	0.05	0.10	0.15
A2	0.85	0.95	1.05
b	0.19	0.25	0.30
b1	0.19	0.22	0.25
c	0.09	0.15	0.20
c1	0.09	0.12	0.16
D	5.00 BSC		
E	6.40 BSC		
E1	4.40 BSC		
e	0.65 BSC		
L	0.50	0.63	0.75
L1	1.00 REF		
L2	0.25 BSC		
ø	0*	4*	8*
TOLERANCE FORM & POSITION			
aaa	0.10		
bbb	0.15		
ccc	0.08		
ddd	0.10		
eee	0.10		

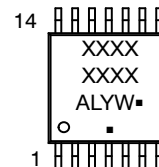
NOTES:

1. DIMENSIONING AND TOLERANCING AS PER ASME Y14.5M, 2018.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION D DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE.
4. DIMENSION E1 DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 PER SIDE.
5. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 TOTAL IN EXCESS OF THE b DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week
▪ = Pb-Free Package
(Note: Microdot may be in either location)

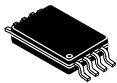
GENERIC
MARKING DIAGRAM*



RECOMMENDED MOUNTING FOOTPRINT
*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DOCUMENT NUMBER:	98ASH70246A	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	TSSOP-14 5.00x4.40x0.95, 0.65P	PAGE 1 OF 1

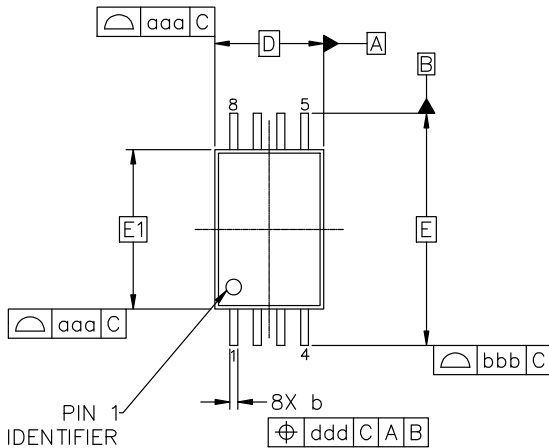
onsemi and onsemi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.



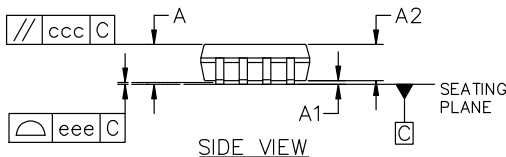
TSSOP-8 3.00x4.00x0.90, 0.65P
CASE 948S
ISSUE D

DATE 24 OCT 2025

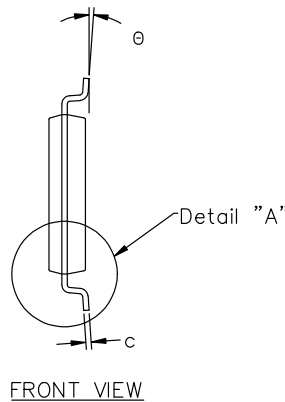
SCALE 2:1



TOP VIEW



SIDE VIEW

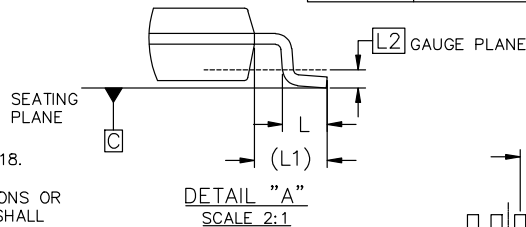


FRONT VIEW

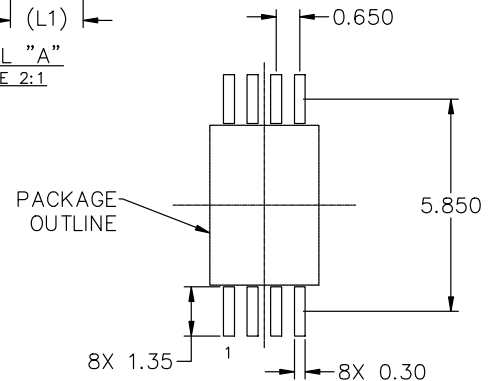
MILLIMETERS			
DIM	MIN	NOM	MAX
A	0.90	1.00	1.10
A1	0.05	0.10	0.15
A2	0.80	0.90	1.00
b	0.19	0.25	0.30
c	0.09	0.15	0.20
D	3.00 BSC		
E	6.40 BSC		
E1	4.40 BSC		
L	0.50	0.60	0.70
L1	1.00 REF		
L2	0.25 BSC		
θ	0°	4°	8°
TOLERANCE FORM & POSITION			
aaa	0.10		
bbb	0.20		
ccc	0.10		
ddd	0.10		
eee	0.05		

NOTES:

1. DIMENSIONING AND TOLERANCING AS PER ASME Y14.5M, 2018.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION "D" DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSION OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE.
4. DIMENSION "E1" DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 PER SIDE.
5. DIMENSION "b" DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08mm TOTAL IN EXCESS OF THE "b" DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OF THE FOOT. MINIMUM SPACE BETWEEN PROTRUSION AND ADJACENT LEAD IS 0.07mm.



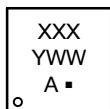
DETAIL "A"
SCALE 2:1



RECOMMENDED MOUNTING FOOTPRINT

*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code
A = Assembly Location
Y = Year
WW = Work Week
▪ = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

DOCUMENT NUMBER:	98AON00697D	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	TSSOP-8 3.00x4.00x0.90, 0.65P	PAGE 1 OF 1

onsemi and onsemi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

onsemi, **Onsemi**, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "**onsemi**" or its affiliates and/or subsidiaries in the United States and/or other countries. **onsemi** owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of **onsemi**'s product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. **onsemi** reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and **onsemi** makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

Technical Library: www.onsemi.com/design/resources/technical-documentation
onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at
www.onsemi.com/support/sales